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Corrigendum: Properties of Cu(In,Ga)Se₂ Thin Films by Co-Evaporation

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In E.-W. Lee et al.'s paper, "Properties of Cu(In,Ga)Se₂ Thin Films by Co-Evaporation", *Molecular Crystals and Liquid Crystals*, Volume 532, 2010, pages 48–54, the authors would have liked to include an Acknowledgment. The updated Acknowledgment information is as follows:

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